Lead-free Green

ZXTN5551G

160V NPN VOLTAGE TRANSISTOR

Features

- BV_{CEO} > 160V
- BV_{EBO} > 6V
- I_C = 600mA Continuous Collector Current
- Low Saturation Voltage (150mV max @10mA)
- h_{FE} specified up to 50mA for a high gain hold up
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

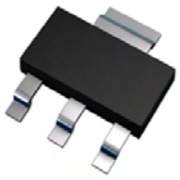
Mechanical Data

- Case: SOT223
- Case material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Leads, Solderable per MIL-STDF-202 Method 208 e3
- Weight: 0.112 grams (Approximate)

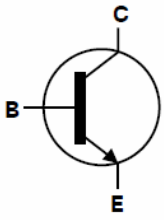
Applications

- High Voltage Amplification

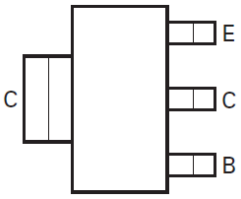
SOT223



Top View



Device Schematic



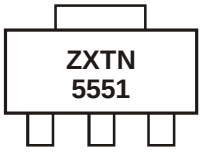
Pin-Out Top View

Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN5551GTA	ZXTN5551	7	12	1,000
ZXTN5551GTC	ZXTN5551	13	12	4,000

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen and Antimony free,"Green" and Lead-Free.
3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at http://www.diodes.com

Marking Information



ZXTN5551 = Product type Marking Code

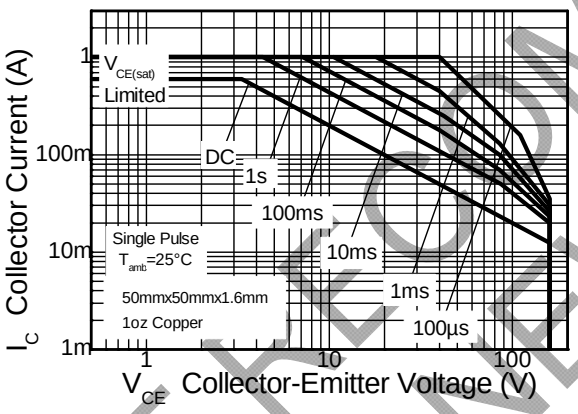
Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	180	V
Collector-Emitter Voltage	V_{CEO}	160	V
Emitter-Base Voltage	V_{EBO}	6	V
Continuous Collector Current	I_C	600	mA

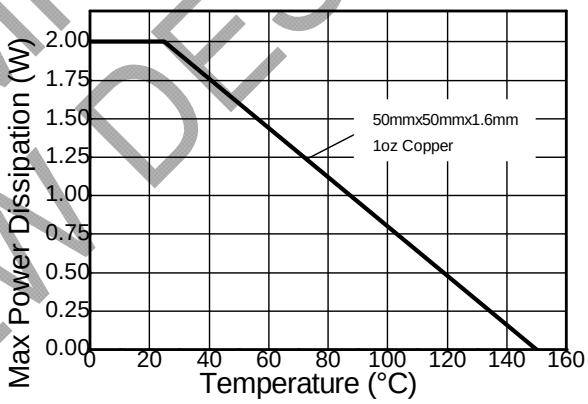
Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P_D	2	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	62.5	°C/W
Thermal Resistance, Junction to Leads (Note 6)	$R_{\theta JL}$	34.05	°C/W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C

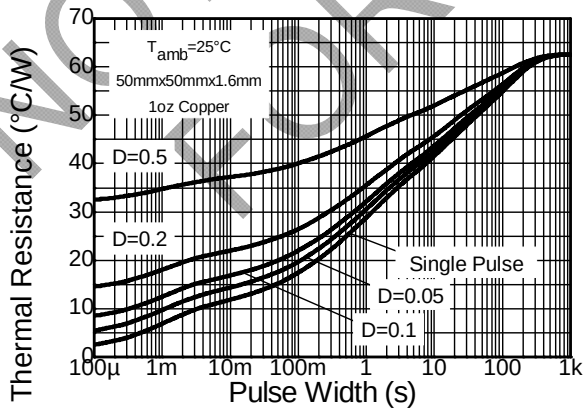
Notes: 5. Device mounted on 50mm X 50mm X 1.6mm FR-4 PCB with high coverage of single sided 1 oz. copper, in still air condition
6. Thermal resistance from junction to solder-point (at the end of the collector lead).



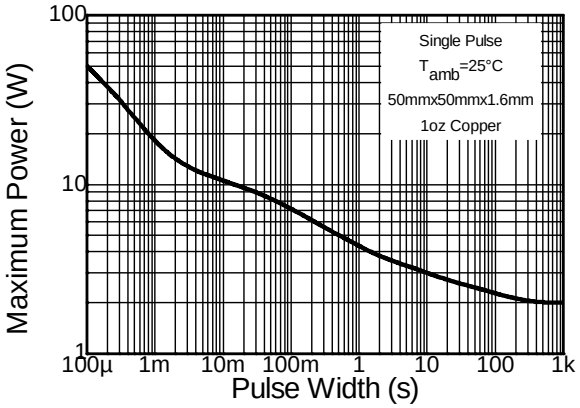
Safe Operating Area



Derating Curve



Transient Thermal Impedance

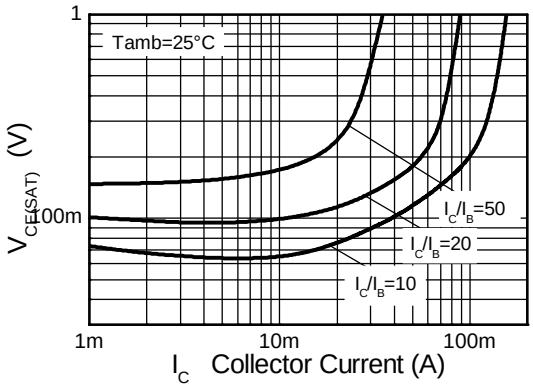


Pulse Power Dissipation

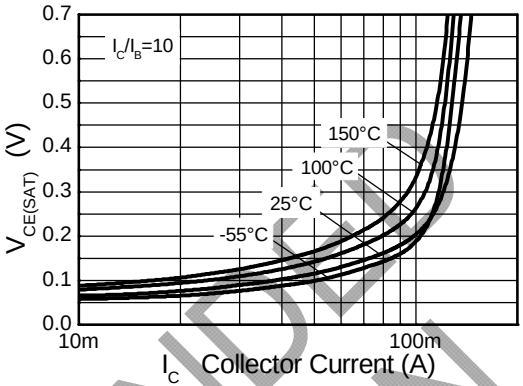
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	180	270	—	V	I_C = 100µA
Collector-Emitter Breakdown Voltage (Note 7)	BV_{CEO}	160	200	—	V	I_C = 1mA
Emitter-Base Breakdown Voltage	BV_{EBO}	6.0	7.85	—	V	I_E = 100µA
Collector Cutoff Current	I_{CBO}	— —	<1 —	50 50	nA µA	V_{CB} = 120V V_{CB} = 120V, T_A = +100°C
Collector-Emitter Saturation Voltage (Note 7)	$V_{CE(sat)}$	— —	65 115	150 200	mV mV	I_C = 10mA, I_B = 1mA I_C = 50mA, I_B = 5mA
Base-Emitter Saturation Voltage (Note 7)	$V_{BE(sat)}$	— —	760 840	1000 1200	mV mV	I_C = 10mA, I_B = 1mA I_C = 50mA, I_B = 5mA
DC Current Gain (Note 7)	h_{FE}	80 80 30	130 145 65	— 250 —	—	V_{CE} = 5V, I_C = 1mA V_{CE} = 5V, I_C = 10mA V_{CE} = 5V, I_C = 50mA
Transition Frequency	f_T	—	130	—	MHz	V_{CE} = 10V, I_C = 10mA, f = 100MHz
Small Signal	h_{FE}	50	—	260	—	V_{CE} = 10V, I_C = 10mA, f = 1kHz
Output Capacitance (Note 7)	C_{obo}	—	—	6	pF	V_{CB} = 10V, f = 1MHz
Delay Time	$t_{(d)}$	—	95	—	ns	V_{CC} = 10V, I_C = 10mA, I_{B1} = I_{B2} = 1mA
Rise Time	$t_{(r)}$	—	64	—	ns	
Storage Time	$t_{(s)}$	—	1256	—	ns	
Delay Time	$t_{(f)}$	—	140	—	ns	

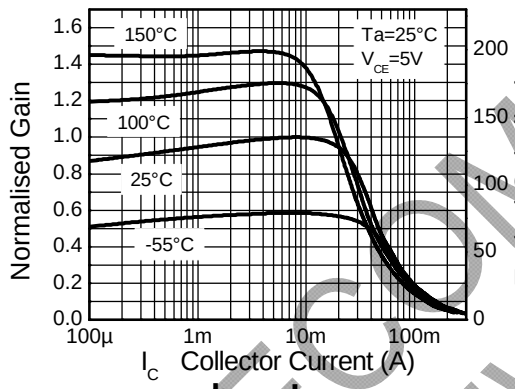
Notes: 7. Pulse Test: Pulse width ≤ 300µs. Duty cycle ≤ 2.0%.



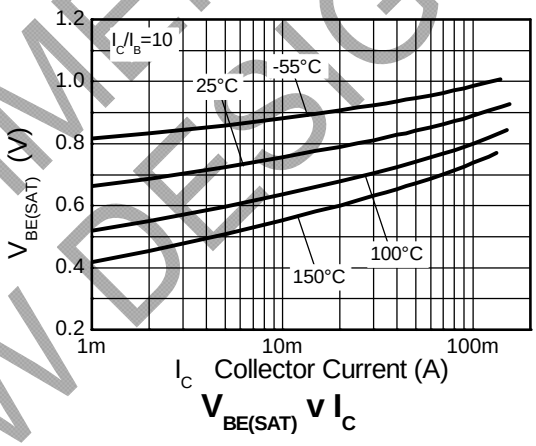
$V_{CE(SAT)}$ v I_C



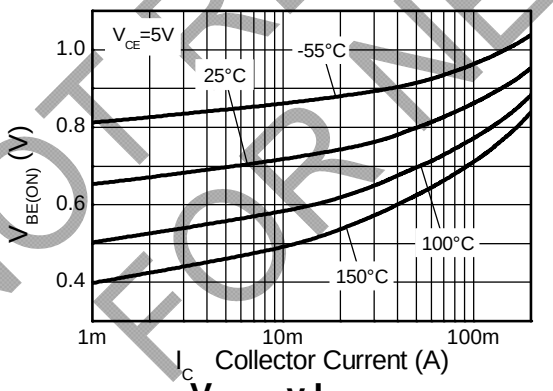
$V_{CE(SAT)}$ v I_C



h_{FE} v I_C



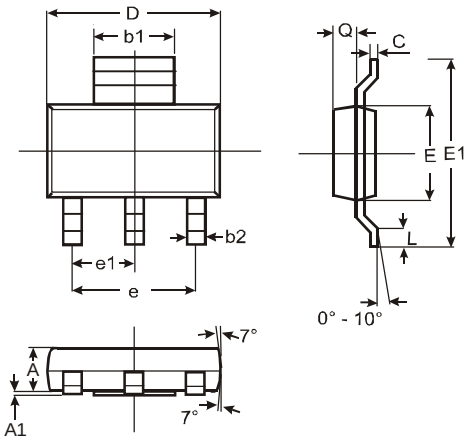
$V_{BE(SAT)}$ v I_C



$V_{BE(ON)}$ v I_C

Package Outline Dimensions

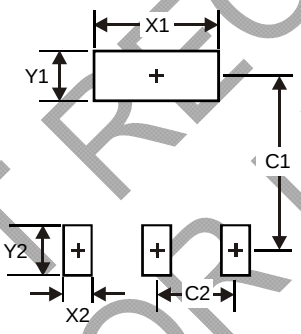
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT223			
Dim	**Min**	**Max**	**Typ**
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b1	2.90	3.10	3.00
b2	0.60	0.80	0.70
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	—	—	4.60
e1	—	—	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
X1	3.3
X2	1.2
Y1	1.6
Y2	1.6
C1	6.4
C2	2.3

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